

主要参数 MAIN CHARACTERISTICS

| | |
|------------------------|--------|
| ID | 94 A |
| VDSS | 500 V |
| Rdson-typ (@Vgs=10V) | 47 mΩ |
| Qg-typ | 225 nC |

用途 APPLICATIONS

| | |
|------|-----------------------|
| 音响功放 | Audio power amplifier |
|------|-----------------------|

产品特性 FEATURES

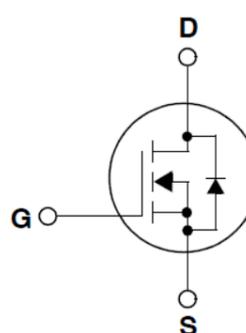
| | |
|--------------------|------------------------------|
| 低栅极电荷 | Low gate charge |
| 低 Crss (典型值 58 pF) | Low Crss (typical 58 pF) |
| 开关速度快 | Fast switching |
| 100%经过雪崩测试 | 100% avalanche tested |
| 100%经过热阻测试 | 100% DVDS tested |
| 100%经过 RG 测试 | 100% Rg tested |
| 内置 FRD | Built-in fast recovery diode |
| 符合 RoHS 标准 | ROHS compliant |

封装形式 Package



TO-264
FHK series

等效电路 Equivalent Circuit



绝对最大额定值 ABSOLUTE RATINGS (Tc=25°C)

| 项目 Parameter | 符号 Symbol | 数值 Value | 单位 Unit |
|---|--|-----------------|------------|
| | | FHK94N50A | |
| 最高漏极-源极直流电压 Drain-Source Voltage | V _{DS} | 500 | V |
| 连续漏极电流* Drain Current -continuous * | I _D (T _c =25°C) | 94 | A |
| | I _D (T _c =100°C) | 65 | A |
| 最大脉冲漏极电流 (注 1) Drain Current – pulse (note 1) | I _{DM} | 376 | A |
| 最高栅源电压 Gate-Source Voltage | V _{GS} | ±30 | V |
| 单脉冲雪崩能量 (注 2) Single Pulsed Avalanche Energy (note 2) | E _{AS} | 6125 | mJ |
| 雪崩电流 (注 1) Avalanche Current (note 1) | I _{AS} | 35 | A |
| 二极管反向恢复最大电压变化速率 (注 3) Peak Diode Recovery dv/dt (note 3) | dv/dt | 30 | V/ns |
| 耗散功率 Power Dissipation | P _D (T _C =25°C) | 1300 | W |
| | -Derate above 25°C | 10.4 | W/°C |
| 最高结温及存储温度 Operating and Storage Temperature Range | T _J , T _{STG} | 150, -55 to 150 | °C |
| 引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes | T _L | 300 | °C |

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature

电特性 ELECTRICAL CHARACTERISTICS

| 项目 Parameter | 符号 Symbol | 测试条件 Tests conditions | 最小 Min | 典型 Typ | 最大 Max | 单位 Units |
|--|-------------------------------------|---|-----------|-----------|-----------|-------------|
| 关态特性 Off –Characteristics | | | | | | |
| 漏-源击穿电压 Drain-Source Voltage | BV _{DSS} | I _D =250μA, V _{GS} =0V | 500 | - | - | V |
| 击穿电压温度特性 Breakdown Voltage Temperature Coefficient | ΔBV _{DSS} /ΔT _J | I _D =250μA, referenced to 25°C | - | 0.5 | - | V/°C |
| 零栅压下漏极漏电流 Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =500V, V _{GS} =0V, T _C =25°C | - | - | 10 | μA |
| | | V _{DS} =400V, T _C =125°C | - | - | 1000 | μA |
| 栅极体漏电流 Gate-body leakage current | I _{GSS} (F/R) | V _{DS} =0V, V _{GS} =±30V | - | - | ±200 | nA |
| 通态特性 On-Characteristics | | | | | | |
| 阈值电压 Gate Threshold Voltage | V _{GS(th)} | V _{DS} = V _{GS} , I _D =250μA | 3.0 | 4.2 | 5.0 | V |
| 静态导通电阻 Static Drain-Source On-Resistance | R _{DS(ON)} | V _{GS} =10V , I _D =30A | - | 47 | 65 | mΩ |
| 动态特性 Dynamic Characteristics | | | | | | |
| 输入电容 Input capacitance | C _{iss} | V _{DS} =25V, V _{GS} =0V, f=1.0MHz | - | 13420 | - | pF |
| 输出电容 Output capacitance | C _{oss} | | - | 1250 | - | |
| 反向传输电容 Reverse transfer capacitance | C _{rss} | | - | 58 | - | |
| 开关特性 Switching Characteristics | | | | | | |
| 延迟时间 Turn-On delay time | t _{d(on)} | V _{DS} =250V, I _D =47A, R _G =1Ω V _{GS} =10V (note 4, 5) | - | 36 | - | ns |
| 上升时间 Turn-On rise time | t _r | | - | 15 | - | ns |
| 延迟时间 Turn-Off delay time | t _{d(off)} | | - | 75 | - | ns |
| 下降时间 Turn-Off Fall time | t _f | | - | 15 | - | ns |
| 栅极电荷总量 Total Gate Charge | Q _g | V _{DS} =250V , I _D =47A , V _{GS} =10V (note 4, 5) | - | 225 | - | nC |
| 栅-源电荷 Gate-Source charge | Q _{gs} | | - | 65 | - | nC |
| 栅-漏电荷 Gate-Drain charge | Q _{gd} | | - | 58 | - | nC |
| 漏-源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings | | | | | | |
| 正向最大连续电流 Maximum Continuous Drain-Source Diode Forward Current | | I _S | - | - | 94 | A |
| 正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current | | I _{SM} | - | - | 376 | A |
| 正向压降 Drain-Source Diode Forward Voltage | V _{SD} | V _{GS} =0V, I _{SD} =94A | - | - | 1.5 | V |
| 反向恢复时间 Reverse recovery time | t _{rr} | V _{GS} =0V, I _S =47A ,dI _F /dt=100A/μs (note 4) | - | 135 | - | ns |
| 反向恢复电荷 Reverse recovery charge | Q _{rr} | | - | 1.3 | - | μC |

热特性 THERMAL CHARACTERISTIC

| 项目 Parameter | 符号 Symbol | FHK94N50A | 单位 Unit |
|--|--------------|-----------|------------|
| 结到管壳的热阻 Thermal Resistance, Junction to Case | Rth(j-c) | 0.096 | °C/W |
| 结到环境的热阻 Thermal Resistance, Junction to Ambient | Rth(j-A) | 30 | °C/W |

注释:

- 1: 脉冲宽度由最高结温限制
- 2: L=10mH, IAS=35A, VDD=50V, RG=25 Ω, 起始结温 TJ=25°C
- 3: ISD ≤94A, di/dt ≤200A/μs, VDD≤BV_{DSS}, 起始结温 TJ=25°C
- 4: 脉冲测试: 脉冲宽度 ≤300μs, 占空比≤2%
- 5: 基本与工作温度无关

Notes:

- 1: Pulse width limited by maximum junction temperature
- 2: L=10mH, IAS=35A, VDD=50V, RG=25 Ω, Start TJ=25°C;
- 3: ISD ≤94A, di/dt ≤200A/μs, VDD≤BV_{DSS}, Starting TJ=25°C
- 4: Pulse Test: Pulse Width ≤300μs, Duty Cycle≤2%
- 5: Essentially independent of operating temperature

特性曲线

(ELECTRICAL CHARACTERISTICS (curves))

Fig. 1. Output Characteristics @ $T_J = 25^\circ\text{C}$

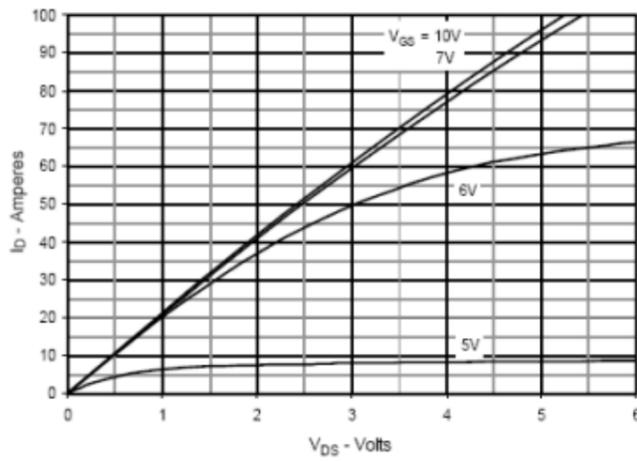


Fig. 2. Extended Output Characteristics @ $T_J = 25^\circ\text{C}$

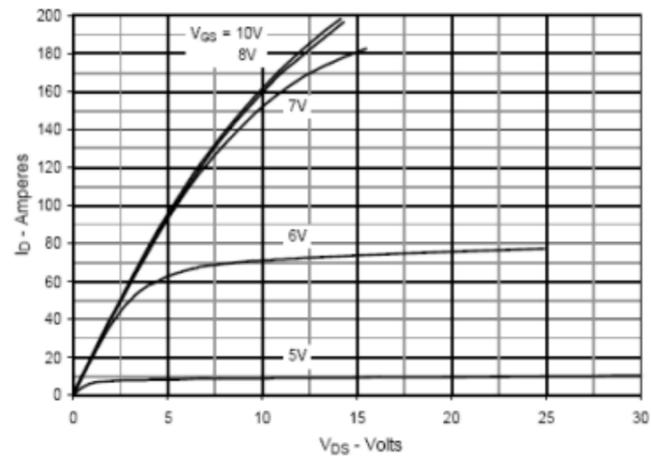


Fig. 3. Output Characteristics @ $T_J = 125^\circ\text{C}$

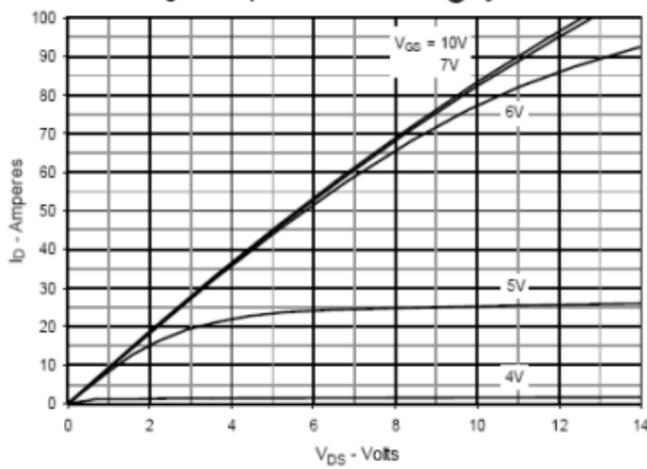


Fig. 4. $R_{DS(on)}$ Normalized to $I_D = 47\text{A}$ Value vs. Junction Temperature

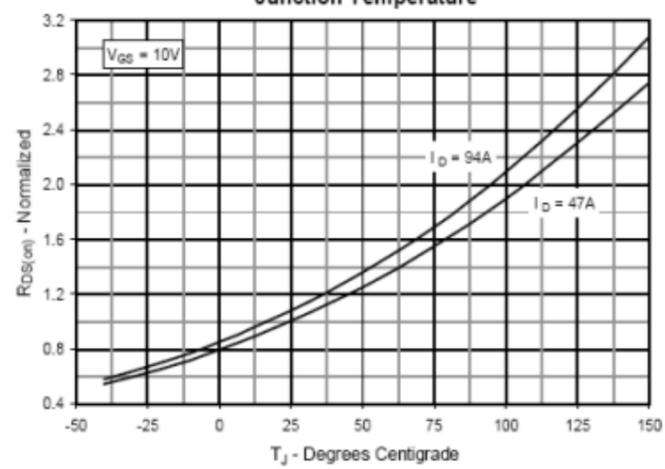


Fig. 5. $R_{DS(on)}$ Normalized to $I_D = 47\text{A}$ Value vs. Drain Current

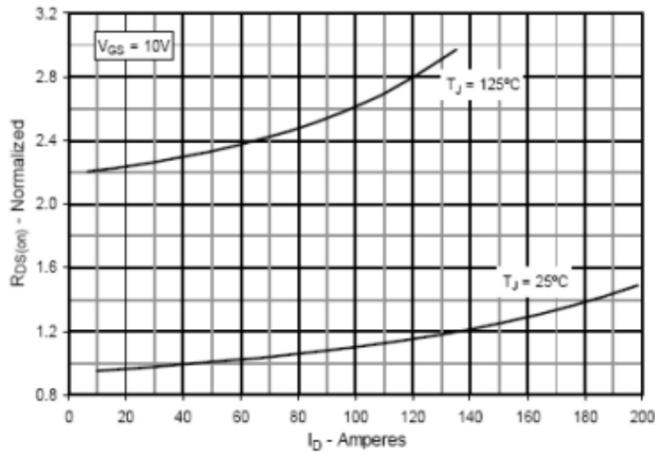


Fig. 6. Maximum Drain Current vs. Case Temperature

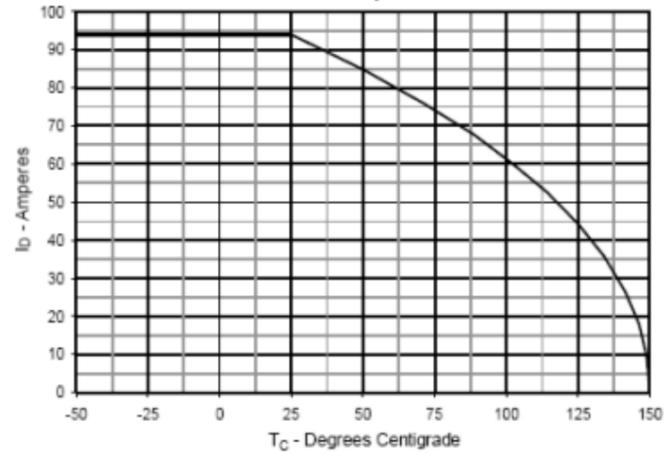


Fig. 7. Input Admittance

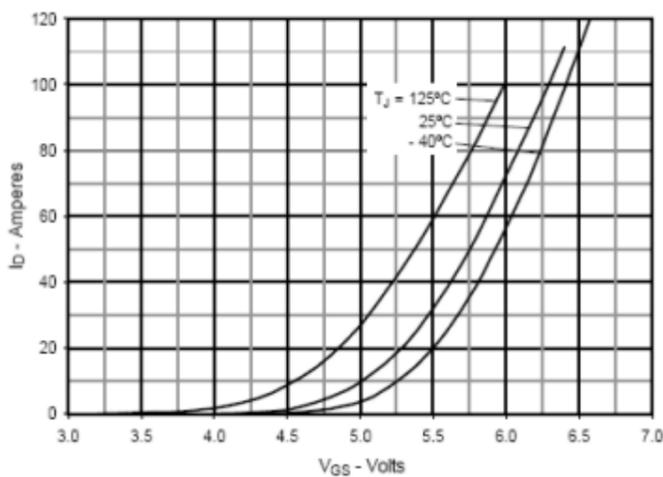
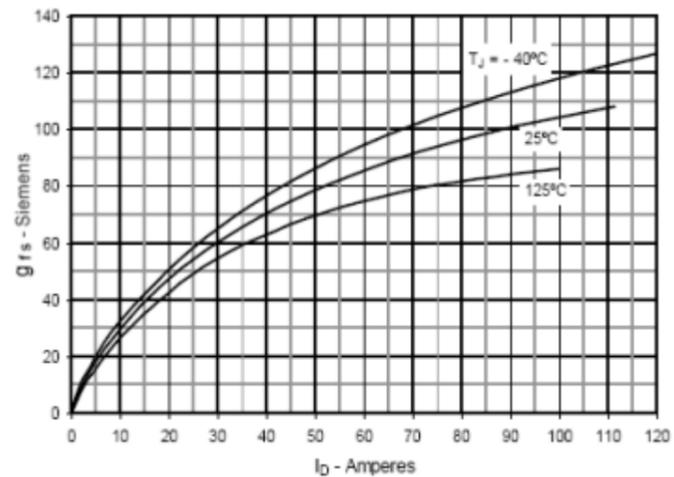
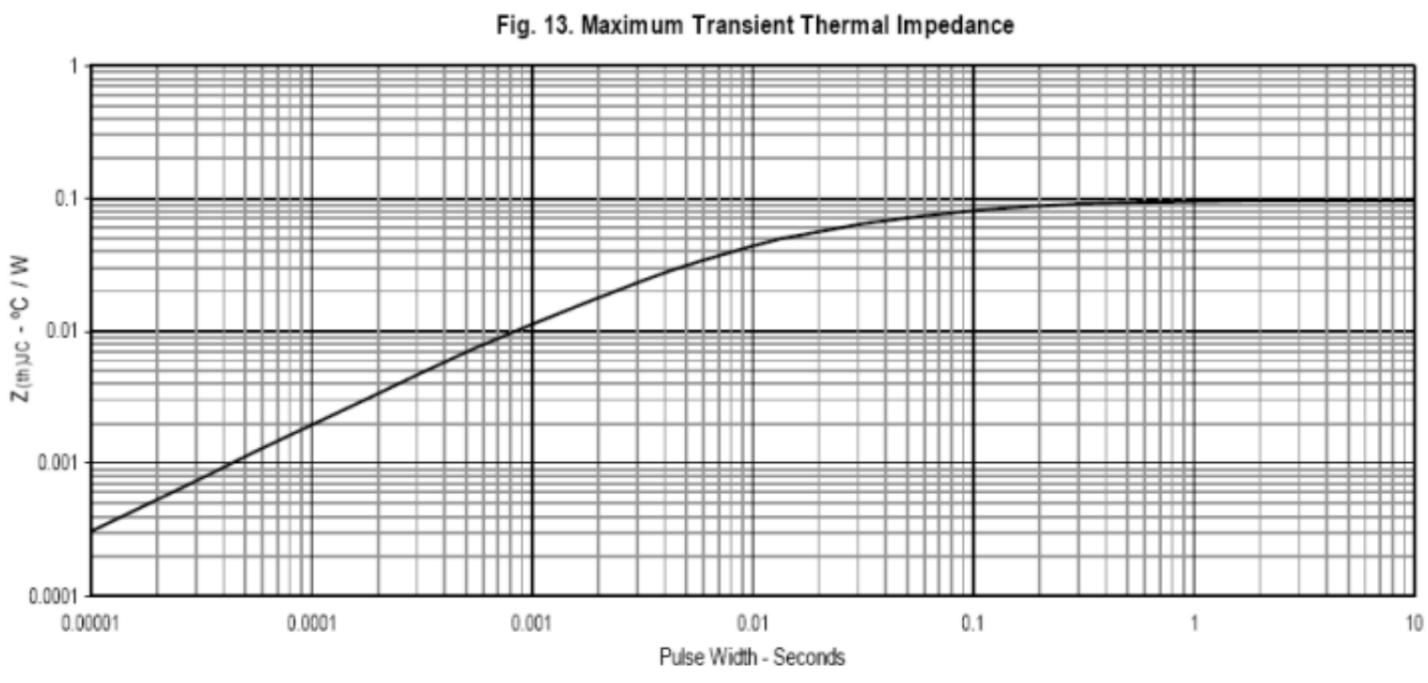
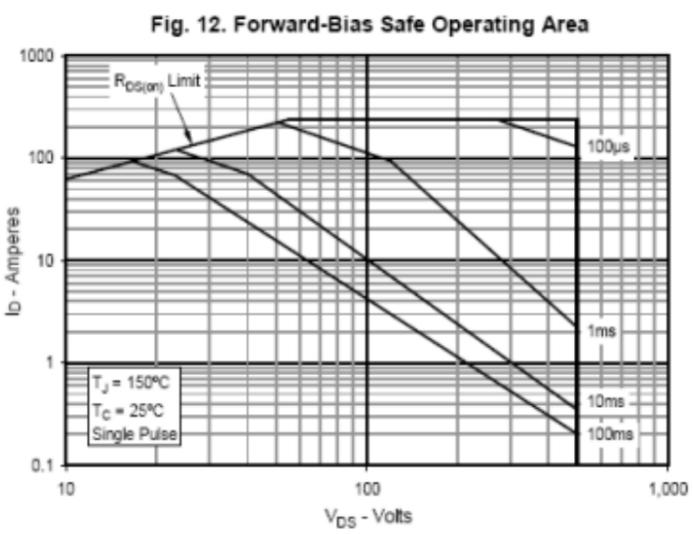
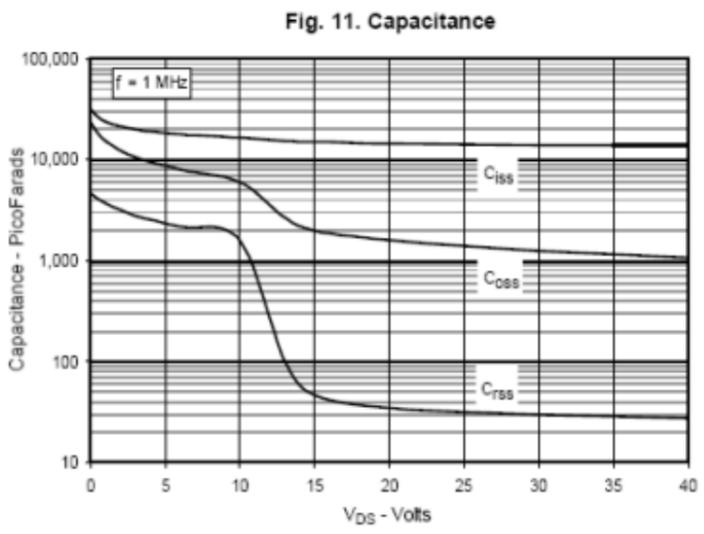
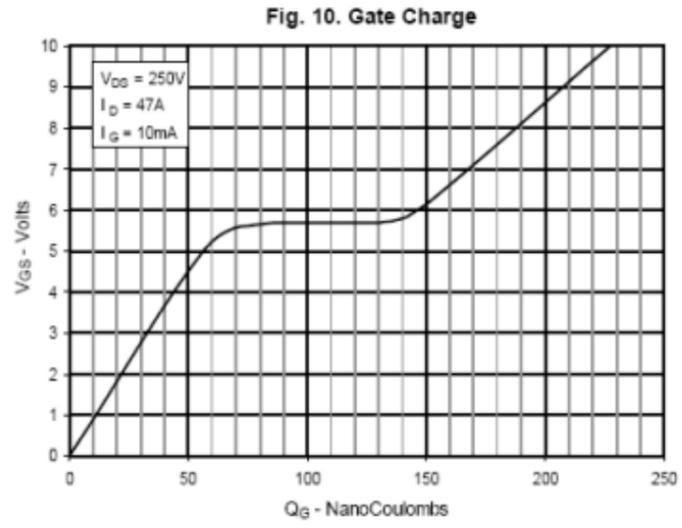
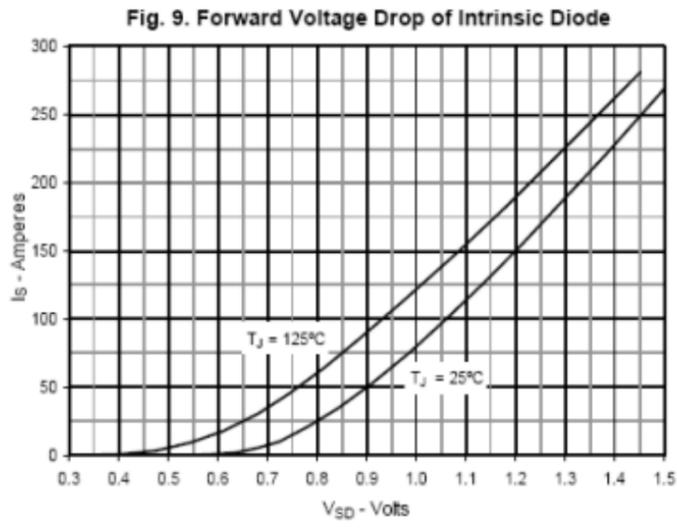


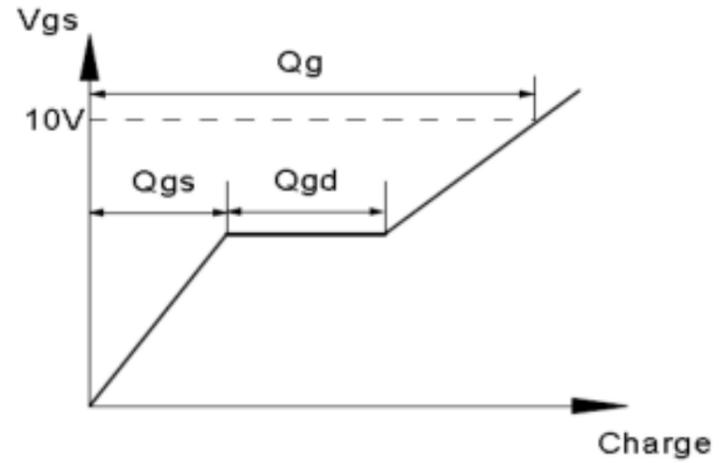
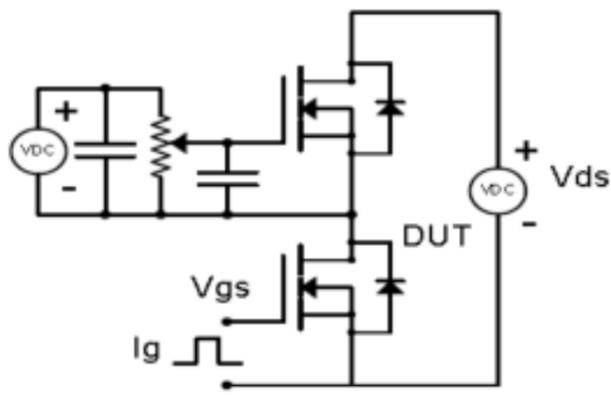
Fig. 8. Transconductance



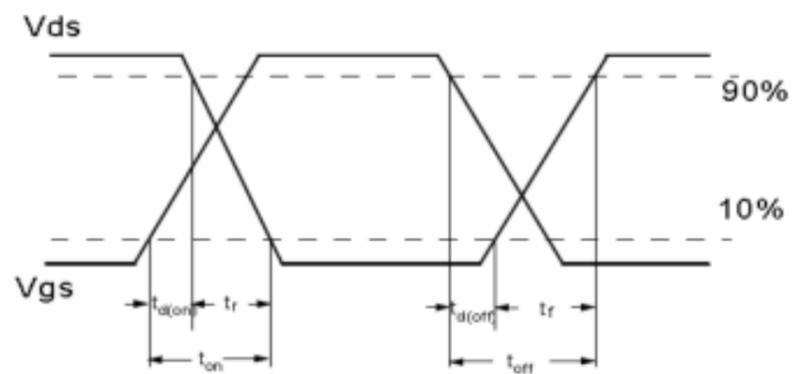
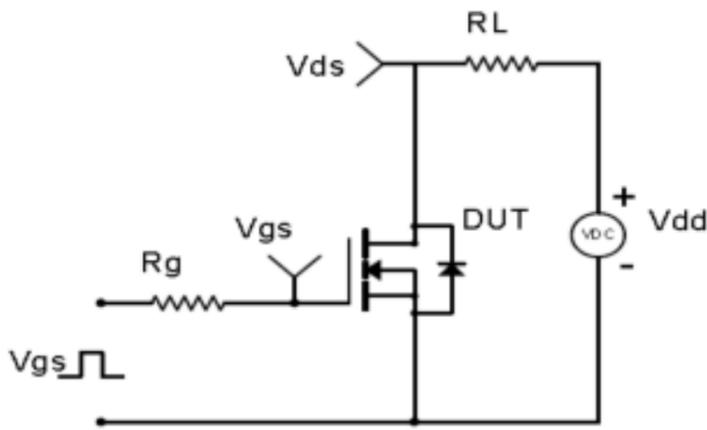


Test Circuit & Waveform

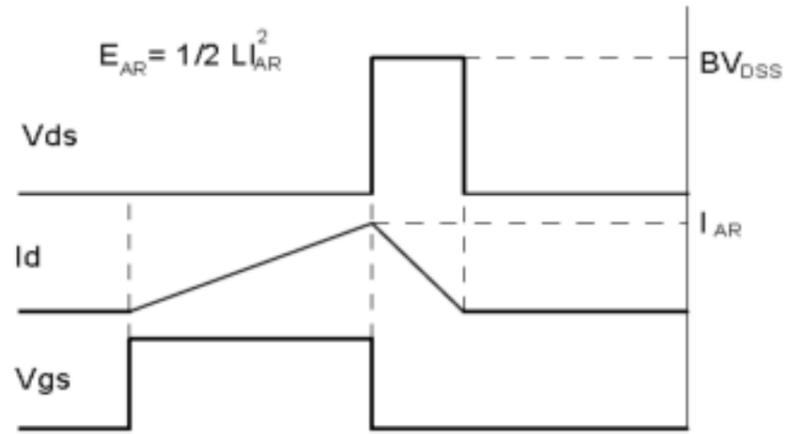
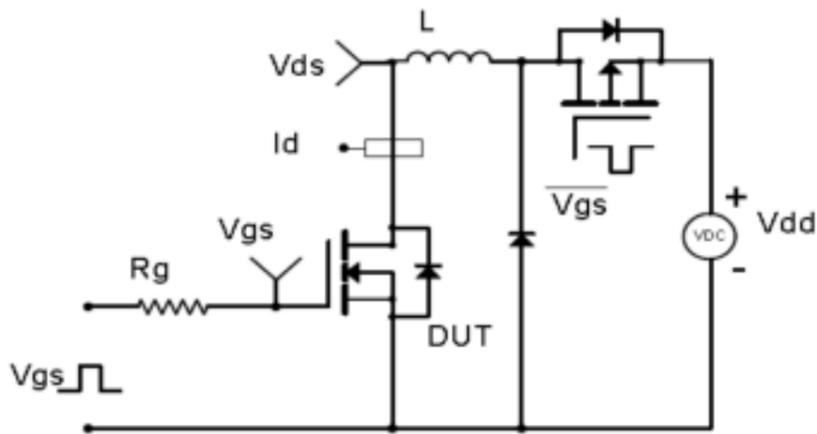
Gate Charge Test Circuit & Waveform



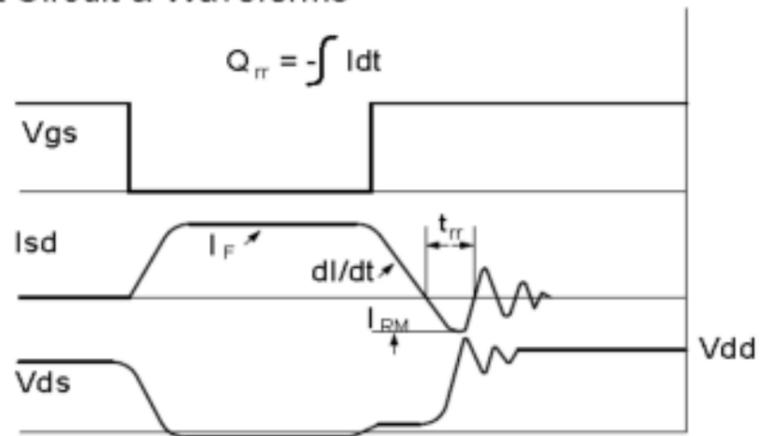
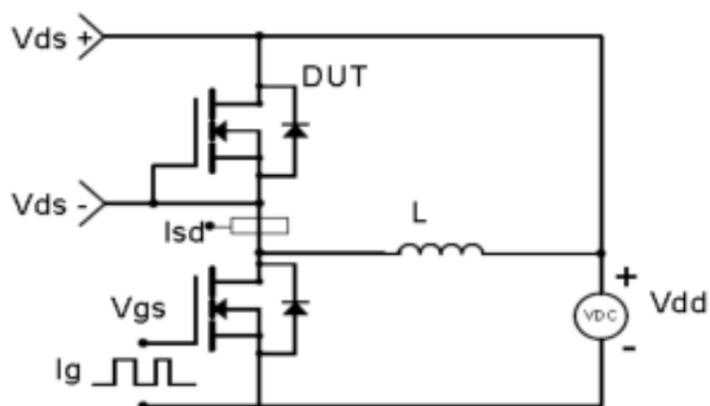
Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



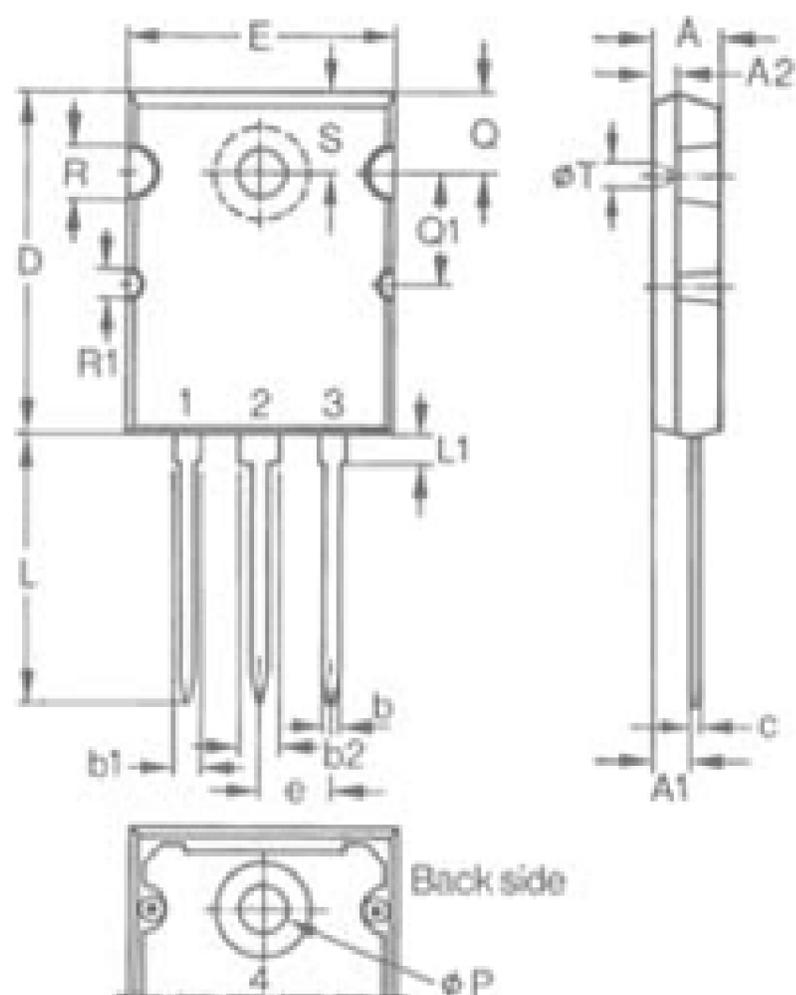
Diode Recovery Test Circuit & Waveforms



外形尺寸:

Package Dimension:

TO-264



Terminals: 1 - Gate
 2 - Drain
 3 - Source
 4 - Drain

| Dim. | Millimeter | | Inches | |
|------|------------|-------|----------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.82 | 5.13 | .190 | .202 |
| A1 | 2.54 | 2.89 | .100 | .114 |
| A2 | 2.00 | 2.10 | .079 | .083 |
| b | 1.12 | 1.42 | .044 | .056 |
| b1 | 2.39 | 2.69 | .094 | .106 |
| b2 | 2.90 | 3.09 | .114 | .122 |
| c | 0.53 | 0.83 | .021 | .033 |
| D | 25.91 | 26.16 | 1.020 | 1.030 |
| E | 19.81 | 19.96 | .780 | .786 |
| e | 5.46 BSC | | .215 BSC | |
| J | 0.00 | 0.25 | .000 | .010 |
| K | 0.00 | 0.25 | .000 | .010 |
| L | 20.32 | 20.83 | .800 | .820 |
| L1 | 2.29 | 2.59 | .090 | .102 |
| P | 3.17 | 3.66 | .125 | .144 |
| Q | 6.07 | 6.27 | .239 | .247 |
| Q1 | 8.38 | 8.69 | .330 | .342 |
| R | 3.81 | 4.32 | .150 | .170 |
| R1 | 1.78 | 2.29 | .070 | .090 |
| S | 6.04 | 6.30 | .238 | .248 |
| T | 1.57 | 1.83 | .062 | .072 |

(Units: mm)